

#### NOT RECOMMENDED FOR NEW DESIGN **USE AH3524Q**

AH3564Q



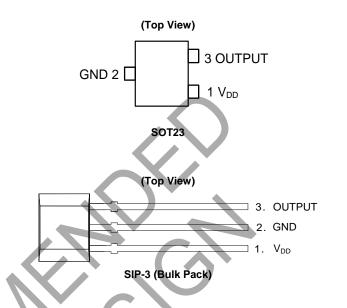
#### HIGH VOLTAGE HIGH SENSITIVITY Lead-free Green AUTOMOTIVE HALL EFFECT OMNIPOLAR SWITCH

### **Description**

The AH3564Q is an AECQ100-qualified high-voltage, high-sensitivity Hall effect omnipolar switch IC designed for position and proximity sensing in automotive applications, such as in seat and seatbelt buckle, steering lock/immobilization, gear stick, transmission actuator and gear position, HVAC compression, wiper, door/trunk closure, and so on. To support a wide range of demanding applications, the design is optimized to operate over the supply range of 3.0V to 28V. With chopper-stabilized architecture and an internal bandgap regulator to provide temperature compensated supply for internal circuits, the AH3564Q provides a reliable solution over the whole operating range. For robustness and protection, the device has a reverse blocking diode with a zener clamp on the supply. The output has an overcurrent limit and a zener clamp.

The single open-drain output can be switched on with south or north pole of sufficient strength. When the magnetic flux density (B) perpendicular to the package is larger than the operate point (BOP), the output is switched on (pulled low) and stays on until the magnetic flux density B is lower than the release point (BRP).

### **Pin Assignments**



#### **Features**

- **Omnipolar Operation**
- High Sensitivity: Bop and BRP of ±40G and ±25G Typical
- Single Open Drain Output with Overcurrent Limit
- 3.0V to 28V Operating Voltage Range
- Chopper Stabilized Design Provides
  - Superior Temperature Stability
  - Minimal Switch Point Drift
  - **Enhanced Immunity to Stress**
- Good RF Noise Immunity
- Reverse Blocking Diode
- Zener Clamp on Supply and Output Pins
- -40°C to +150°C Operating Temperature
- ESD: HBM > 8kV. CDM: >2kV
- Industry Standard SOT23 and SIP-3 (Ammo Pack), SIP-3 (Bulk Pack) Packages
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free, "Green" Device (Note 3)

### **Applications**

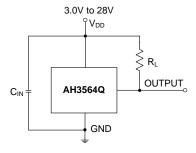
- Position and Proximity Sensing in Automotive Applications.
- Open and Close Detect
- Position Detect
- Level Detect
- Flow Meters
- Contactless Switches
- Seatbelt Buckle
- Seat Position

Notes:

- No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



# **Typical Applications Circuit**



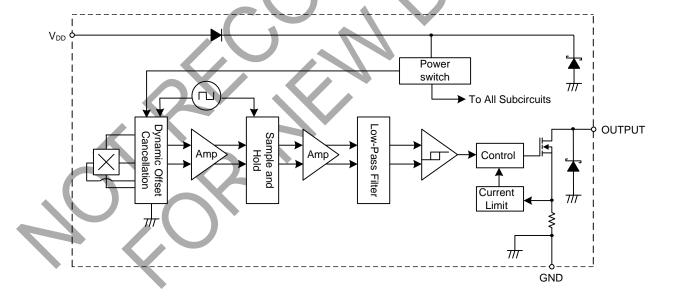
Note: 4. C<sub>IN</sub> is for power stabilization and to strengthen the noise immunity, the recommended capacitance is 10nF ~ 100nF. R<sub>L</sub> is the pull-up resistor.

## **Pin Descriptions**

Package: SOT23 and SIP-3 (Ammo Pack), SIP-3 (Bulk Pack)

Pin Number	Pin Name	Function
1	$V_{DD}$	Power Supply Input
2	GND	Ground
3	OUTPUT	Output Pin

# **Functional Block Diagram**





# Absolute Maximum Ratings (Note 5 & 6) (@TA = +25°C, unless otherwise specified.)

Symbol	Characteristic		Value	Unit	
VDD	Supply Voltage (Note 6)		32	V	
Vddr	Reverse Supply Voltage (Note 6)		-32	V	
Vout_max	Output Off Voltage (Note 6)		32	V	
Іоит	Continuous Output Current		60	mA	
lout_r	Reverse Output Current		-50	mA	
В	Magnetic Flux Density	Unlimited			
P <sub>D</sub>	Package Power Dissipation	SIP-3 (Ammo Pack), SIP-3 (Bulk Pack)	550	mW	
		SOT23	230	7	
Ts	Storage Temperature Range		-65 to +165	°C	
TJ	Maximum Junction Temperature		+150	°C	
ESD HBM	Electros Static Discharge Withstand—Human Body Model (HM	B)	8	kV	
ESD MM	Electros Static Discharge Withstand—Machine Model (MM)		800	V	
ESD CDM	Electros Static Discharge Withstand—Charged Device Model (	CDM)	2	kV	

Notes:

- 5. Stresses greater than the 'Absolute Maximum Ratings' specified above may cause permanent damage to the device. These are stress ratings only; functional operation of the device at these or any other conditions exceeding those indicated in this specification is not implied. Device reliability may be affected by exposure to absolute maximum rating conditions for extended periods of time.
- 6. The absolute maximum V<sub>DD</sub> of 32V is a transient stress rating and is not meant as a functional operating condition. It is not recommended to operate the device at the absolute maximum rated conditions for any period of time.

### Recommended Operating Conditions (@TA = -40°C to +150°C, unless otherwise specified.)

Symbol	Parameter	Rating	Unit		
$V_{DD}$	Supply Voltage	Operating		3.0 to 28	V
T <sub>A</sub>	Operating Temperature Range	Operating		-40 to +150	°C

### Electrical Characteristics (Note 7 & 8) (@TA = -40°C to +150°C, VDD = 3V to 28V, unless otherwise specified.)

Symbol	Parameter	Condition	Min	Тур	Max	Unit
Vout_on	Output ON Voltage	IOUT = 20mA, B > BOP	_	0.2	0.4	V
ILKG	Output Leakage Current (When Output is Off)	Vout = 28V, B < B <sub>RP</sub> , Output Off	1	<0.1	10	μA
IDD	Supply Current	Output open, T <sub>A</sub> = +25°C	_	3	3.5	mA
IDD	Supply Current	Output open, $T_A = -40^{\circ}C$ to $+150^{\circ}C$	_	_	4	mA
		$V_{DD} = -18V$ , $T_A = +25^{\circ}C$	_	0.6	_	μA
I <sub>DD</sub> R	Reverse Supply Current	$V_{DD} = -18V$ , $T_A = -40^{\circ}C$ to $+150^{\circ}C$	_	0.6	1500	μA
IDD_K	reverse Supply Current	$V_{DD} = -28V, T_A = +25^{\circ}C$	-	1.6	_	μA
		$V_{DD} = -28V$ , $T_A = -40^{\circ}C$ to $+150^{\circ}C$		1.6	2500	μA
t <sub>P_ON</sub>	Device Power-On Time (Start-up Time)	$V_{DD} >= 3V, B > B_{OP}$ (Note 7)		10	-	μs
fc	Chopping Frequency	_	-	800	_	kHz
tp	Response Time Delay (Time from magnetic threshold reached to the start of the output rise or fall)	(Note 9)	_	3.75	_	μs
tR	Output Rising Time (External pull-up resistor R <sub>L</sub> and load capacitance dependent)	$R_L = 1k\Omega$ , $C_L = 20pF$	ı	0.2	1	μs
t <sub>F</sub>	Output Falling Time (Internal switch resistance and load capacitance dependent)	$R_L = 1k\Omega$ , $C_L = 20pF$		0.1	1	μs
locL	Output Current Limit	B > Bop, (Note 10)	30		55	mA
Vz	Zener Clamp Voltage	I <sub>DD</sub> = 5mA	28	_	_	V

Notes:

- 7. When power is initially turned on, Vop must be within its correct operating range (3.0V to 28V) to guarantee the output sampling. The output state is valid after the start-up time of 10µs typical from the operating voltage reaching 3V.
- 8. Typical values are defined at T<sub>A</sub> = +25°C, V<sub>DD</sub> = 12V. Maximum and minimum values over the operating temperature range is not tested in production but guaranteed by design, process control and characterization.
- 9. Guaranteed by design, process control and characterization. Not tested in production.
- 10. The device will limit the output current  $I_{OUT}$  to current limit of  $I_{OCL}$ .

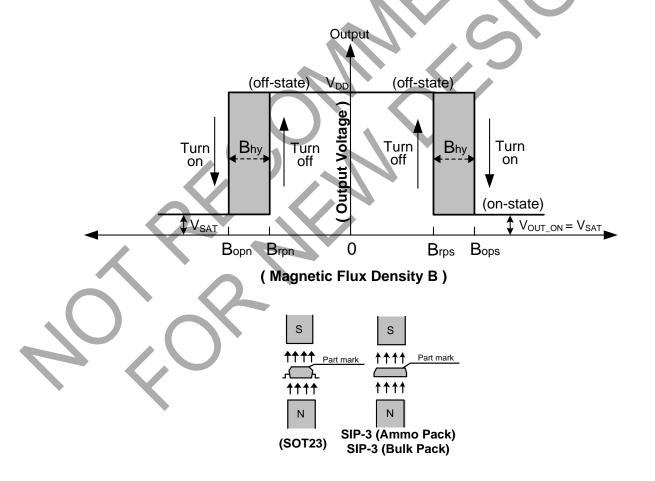


# Magnetic Characteristics (Note 11 &12) (T<sub>A</sub> = -40°C to +150°C, V<sub>DD</sub> = 3.0V to 28V, unless otherwise specified.)

				(1	mT=10 G	auss)
Symbol	Parameter	Condition	Min	Тур	Max	Unit
Dane (South Dolo to the Dort Marking Cide)		V <sub>DD</sub> = 12V, T <sub>A</sub> = +25°C	_	40	_	
Bops (South Pole to the Part Marking Side)	On susting Point	T <sub>A</sub> = -40°C to +125°C	20	40	60	
D (North Dole to the Dort Marking Cide)	Operation Point	V <sub>DD</sub> = 12V, T <sub>A</sub> = +25°C	_	-40	_	
B <sub>OPN</sub> (North Pole to the Part Marking Side)		$T_A = -40^{\circ}C \text{ to } +125^{\circ}C$	-60	-40	-20	
D (South Dolo to the Dort Marking Cide)		V <sub>DD</sub> = 12V, T <sub>A</sub> = +25°C		25	_	Gauss
B <sub>RPS</sub> (South Pole to the Part Marking Side)	Dalassa Dalas	$T_A = -40^{\circ}C \text{ to } +125^{\circ}C$	10	25	45	Gauss
D (South Dolo to the Dort Marking Cide)	Release Point	V <sub>DD</sub> = 12V, T <sub>A</sub> = +25°C	/-	-25	_	
B <sub>RPS</sub> (South Pole to the Part Marking Side)		$T_A = -40^{\circ}C \text{ to } +125^{\circ}C$	-45	-25	-10	
D (ID ID I	Liveteresia (Nieto 12)	V <sub>DD</sub> = 12V, T <sub>A</sub> = +25°C	\ <del>-</del> /	15	_	
B <sub>HY</sub> ( B <sub>OPX</sub>  - B <sub>RPX</sub>  )	Hysteresis (Note 13)	$T_A = -40$ °C to +125°C	9	15	22	

Notes: 11. When power is initially turned on, V<sub>DD</sub> must be within its correct operating range (3.0V to 28V) to guarantee the output sampling. The output state is valid after the start-up time of 10µs typical from the operating voltage reaching 3V.

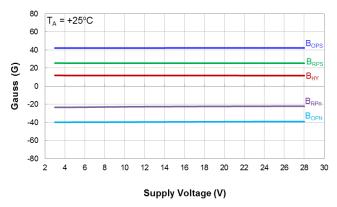
- 12. Typical values are defined at  $T_A = +25^{\circ}C$ ,  $V_{DD} = 12V$ . Maximum and minimum values over the operating temperature range is not tested in production but guaranteed by design, process control and characterization.
- 13. Maximum and minimum hysteresis is guaranteed by design, process control and characterization



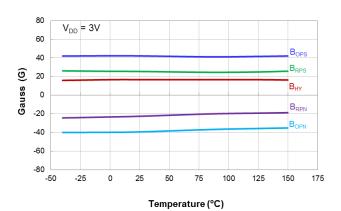


### **Typical Operating Characteristics**

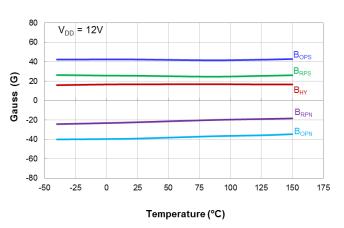
#### Output Switch Operate and Release Points (Magnetic Thresholds)—BOP and BRP



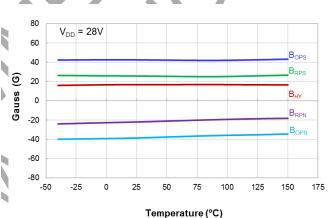
Switch Points  $\mathbf{B}_{\text{OPS}}$  and  $\mathbf{B}_{\text{RPS}}$  vs Supply Voltage



Switch Points  $\mathbf{B}_{\text{OPS}}$  and  $\mathbf{B}_{\text{RPS}}$  vs Temperature

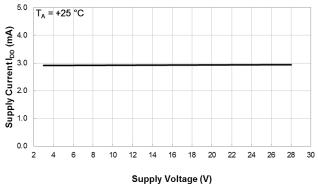


Switch Points  $\mathbf{B}_{\text{OPS}}$  and  $\mathbf{B}_{\text{RPS}}$  vs Temperature

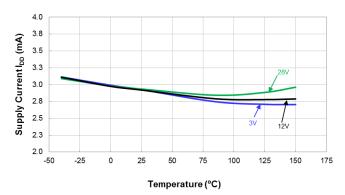


Switch Points  $\mathbf{B}_{\text{OPS}}$  and  $\mathbf{B}_{\text{RPS}}$  vs Temperature





Supply Current vs Supply Voltage

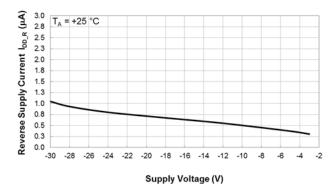


Supply Current vs Temperature

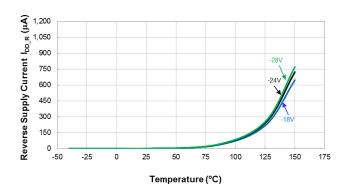


### **Typical Operating Characteristics** (continued)

#### **Supply Reverse Current**

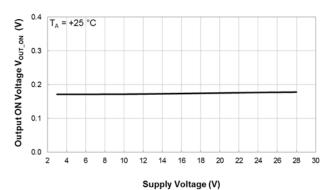


Reverse Supply Current vs Supply Voltage

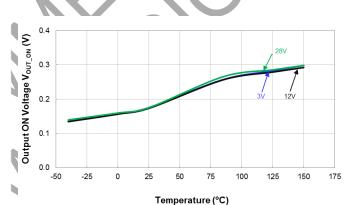


Reverse Supply Current vs Temperature

### **Output Switch On Voltage**

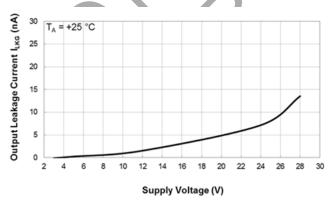


Output ON Voltage vs Supply Voltage

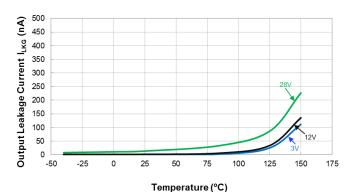


Output ON Voltage vs Temperature

#### **Output Switch Leakage Current**





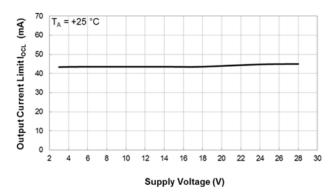


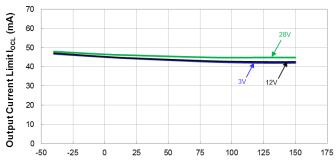
**Output Leakage Current vs Temperature** 



# **Typical Operating Characteristics (cont.)**

#### **Output Current Limit**





Output Current Limit vs Supply Voltage

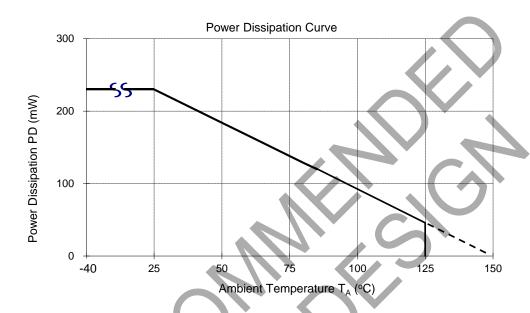
Temperature (°C)
Output CurrentLimit vs Temperature



## **Thermal Performance Characteristics**

### (1) Package Type: SOT23

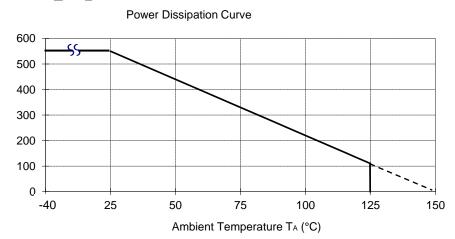
T <sub>A</sub> (°C)	25	50	60	70	80	85	90	100	105	110	120	125	130	140	150
P <sub>D</sub> (mW)	230	184	166	147	129	120	110	92	83	74	55	46	37	18	0



# (2) Package Type: SIP-3 (Ammo Pack), SIP-3 (Bulk Pack)

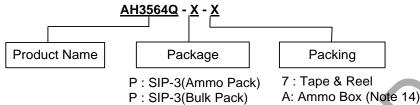
T <sub>A</sub> (°C)	25	50	60	70	80	85	90	100	105	110	120	125	130	140	150
P <sub>D</sub> (mW)	550	440	396	362	308	286	264	220	198	176	132	110	88	44	0







## **Ordering Information**



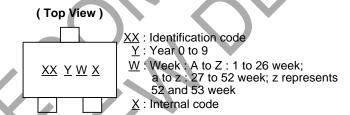
SA: SOT23 B: Bulk (Note 15)

	Bookogo		I	Bulk	7" Tape an	d Reel	Amm	ю Вох
Part Number	Package Code	Packaging	Quantity	Part Number Suffix	Quantity	Part Number Suffix	Quantity	Part Number Suffix
AH3564Q-P-A	Р	SIP-3 (Ammo Pack)	NA	NA	NA	NA	4000/Box	-A
AH3564Q-P-B	Р	SIP-3 (Bulk Pack)	1000	-B	NA	NA	NA	NA
AH3564Q-SA-7	SA	SOT23	NA	NA	3000/Tape & Reel	-7	NA	NA

14. Ammo Box is for SIP-3 (Ammo Pack) Spread Lead. 15. Bulk is for SIP-3 (Bulk Pack) Straight Lead. Notes:

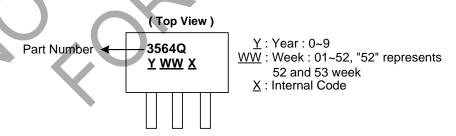
### **Marking Information**

#### (1) Package Type: SOT23



Part Number	Package	Identification Code
AH3564Q	SOT23	Z4

#### (2) Package Type: SIP-3 (Ammo Pack), SIP-3 (Bulk Pack)



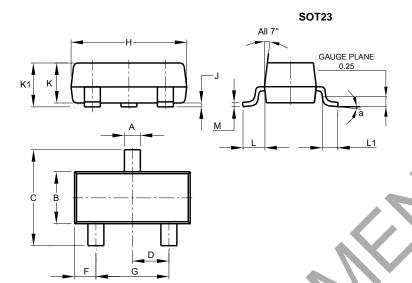
Part Number	Package	Identification Code
AH3564Q	SIP-3 (Ammo Pack)	3564Q
AH3564Q	SIP-3 (Bulk Pack)	3564Q



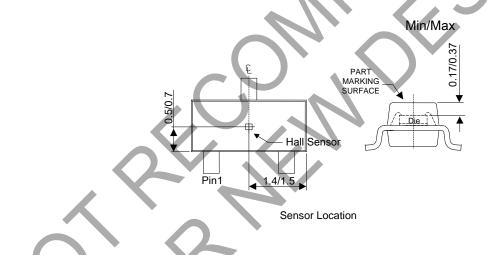
# Package Outline Dimensions (All dimensions in mm.)

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### (1) Package Type: SOT23



SOT23								
Dim	Min	Max	Тур					
Α	0.37	0.51	0.40					
В	1.20	1.40	1.30					
С	2.30	2.50	2.40					
D	0.89	1.03	0.915					
F	0.45	0.60	0.535					
G	1.78	2.05	1.83					
Н	2.80	3.00	2.90					
J	0.013	0.10	0.05					
K	0.890	1.00	0.975					
K1	0.903	1.10	1.025					
L	0.45	0.61	0.55					
L1	0.25	0.55	0.40					
М	0.085	0.150	0.110					
а	0°	8°	_					
All	Dimens	ions in	mm					

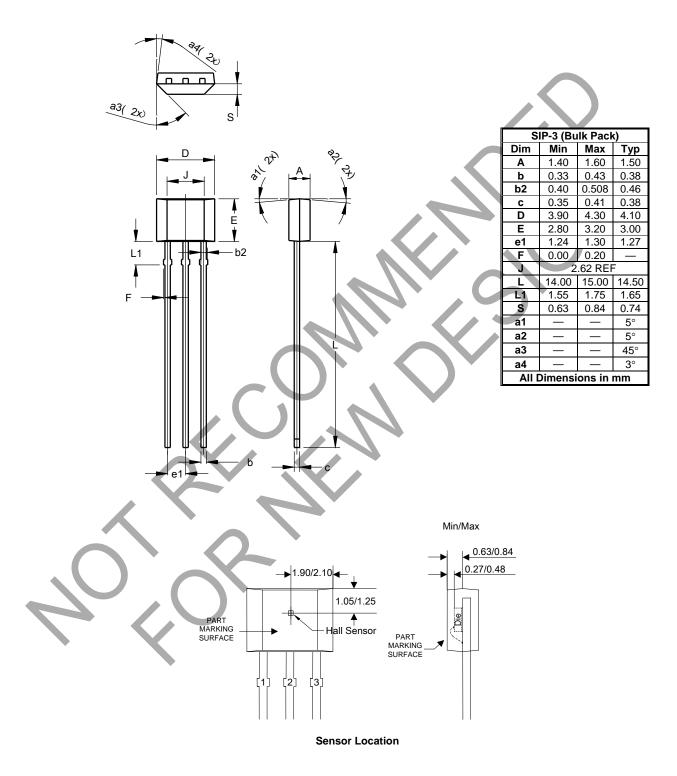




### Package Outline Dimensions (continued) (All dimensions in mm.)

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### (2) Package Type: SIP-3 (Bulk Pack)

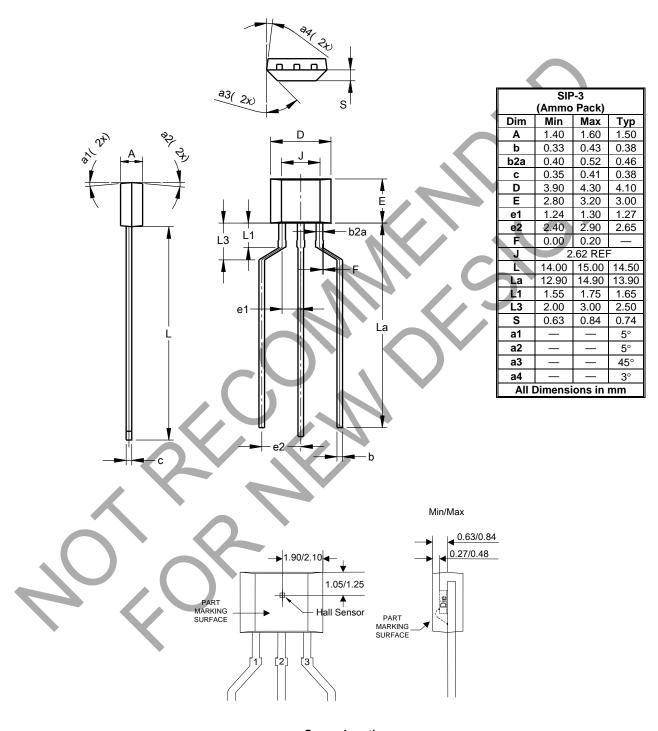




## Package Outline Dimensions (cont.) (All dimensions in mm.)

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### (3) Package Type: SIP-3 (Ammo Pack)



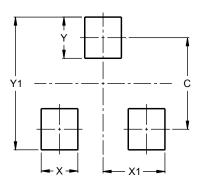
**Sensor Location** 



# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### (1) Package Type: SOT23



Dimensions	Value (in mm)
C	2.0
Х	0.8
X1	1.35
Υ	0.9
Y1	2.9



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